NSN 5961-01-077-6326

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-077-6326 **Inclosure Material:** Plastic **Overall Length:** 0.265 inches **Overall Height:** 0.075 inches **Overall Width:** 0.250 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 75.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: